L Number	Hits		DB	Time stamp
-	334	1	USPAT;	2002/11/25 17:12
		magnetoresistance or applied near field) and	US-PGPUB;	
		(ferromagnetic or ferromagnet or iron or fe	EPO; JPO;	
		or cobalt or cofe or co-fe or ni-fe or nife)	DERWENT;	
		and (nanotube or fullerene or	IBM_TDB	
		quasi-one-dimension\$2 or one-dimension\$2 or ldeg)		
-	36	(magnetoelectric or magnetoresistive or	USPAT;	2002/11/22 14:18
		magnetoresistance) and (ferromagnetic or	US-PGPUB;	
		ferromagnet) and (nanotube or fullerene or	EPO; JPO;	
		quasi-one-dimension\$2 or one-dimension\$2 or	DERWENT;	
	1.50	1deg)	IBM_TDB	
_	150	I the Description of magnetorestrative of	USPAT;	2002/11/22 15:08
		magnetoresistance or ferromagnetic or	US-PGPUB;	
		ferromagnet) and (nanotube or fullerene or	EPO; JPO;	
		quantum near wire)	DERWENT;	
_	35	(magneteelegtmig en magneteelegt)	IBM_TDB	
	33	(magnetoelectric or magnetoresistive or magnetoresistance) and (ferromagnetic or	USPAT;	2002/11/22 15:09
		ferromagnet or magnet or magnetic) and	US-PGPUB;	
		(nanotube or fullerene or quantum near wire	EPO; JPO;	
		or nanowire or nano adj tube or nano adj	DERWENT;	
		wire or quantum adj tube)	IBM_TDB	
-	78	(magnetic adj head or magnetoresistive near2	HODAM	0000/11/05
	. •	head or magnetoresistance near2 head or mr	USPAT; US-PGPUB:	2002/11/25 14:27
		near2 head or spin adj valve or magnetic		
		near2 tunnel or read adj head) and (free or	EPO; JPO; DERWENT;	
		pinned or spacer) near4 (carbon)	IBM TDB	
-	2203	Co near3 ferromagnetic	USPAT;	2002/11/25 15:31
		= - · ·····g = -	US-PGPUB;	2002/11/25 15:31
		•	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	66	(magnetic adj head or magnetoresist\$4 near	USPAT;	2002/11/25 15:57
		head or magnetoresist\$4 near sensor or mr	US-PGPUB;	,,,,
		near head or spin near valve or magnetic	EPO; JPO;	
		near2 tunnel) and (free or pinned or spacer	DERWENT;	
]	or channel) near2 (silicon or boron adj	IBM_TDB	
		nitride or Si or BN)	_	